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Substitute for form 1449A/PTO				Complete if Known			
INFO	ORMATION	DIS	CLOSURE	Application Number	TBA, Continuation of SN 10/315,030		
STATEMENT BY APPLICANT				. Filing Date	herewith		
				First Named Inventor	.Tomoharu Tanaka		
•				Group Art Unit	2824 (parent)	_	
(use as many sheets as necessary)			necessary)	Examiner Name	Son T. Dinh (parent)		
Sheet	1	Of.	2	Attorney Docket Number	001701.00193		

Examiner Initials •	Cite. No.1	Occument Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant
		Number - Kind Code <sup>2</sup> (if known)		Citad Cottainerit	Passages or Relevant Figures Appear
41)		US-5,299,162	03-29-1994	Kim et al.	
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5		US-6,208,573B1	03-27-2001	Tanaka et al.	

		FOREIG	N PATENT DO	CUMENTS		
Examiner Initials*	Cite No.1	Foreign Patent Document  Country Code <sup>3</sup> - Number <sup>4</sup> - Kind Code <sup>5</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T⁵
<u> </u>	٠,	JP 08-279297	10-22-1996	Samsung Electron Co Ltd.		Abstr.
S		JP 07-230695	08-29-1995	Toshiba Corp.		Abstr.
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Examiner Signature Date Consid	ered ////04
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<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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Compl te if Known Substitute for form 1449A/PTO TBA; Continuation of SN 10/315,030 Application Number INFORMATION DISCLOSURE Filing Date herewith STATEMENT BY APPLICANT First Named Inventor Tomoharu Tanaka Group Art Unit 2824 (parent) (use as many sheets as necessary) **Examiner Name** Son T. Dinh (parent) Sheet 001701.00193 Attorney Docket Number

		OTHER PRIOR ART NON PATENT LITERATURE DOCUMENTS					
Examiner Initials *	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.					
GD		Tae-Sung JUNG et al., "A3,3V 128 Mb Multi-Level NAND Flash Memory for Mass Storage Applications," ISSCC Digest of Technical papers, pp. 32-33, Feb. 1996					
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